

**P2\_173****Volkov-Pankratov states and the anomalous screening of topological insulators**

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**P2\_174****Magnetic field-induced topological phase transition in Pb<sub>1-x</sub>Sn<sub>x</sub>Se**

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**P2\_175****Ground State Transition Diagram in Al-InSb Majorana Islands**

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*G. Budkin (Russia), L. Golub (Russia), E. Ivchenko (Russia), S. Ganichev (Germany)*

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*D. Babajanov (Uzbekistan), H. Matyaqubov (Uzbekistan)*

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**P2\_196****Superconductivity above the Transition Temperature Induced by Harnessed Dissipation in Superconductor-Semiconductor Junctions**

*Y. Yamada (Japan), T. Ogawa (Japan)*

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*M. Onizaki (Japan), S. Katsumoto (Japan), T. Nakamura (Japan), A. Endo (Japan), Y. Hashimoto (Japan)*